

1. General description

Planar passivated four quadrant triac in a SOT428 (DPAK) surface-mountable plastic package intended for use in bidirectional switching and phase control applications.

2. Features and benefits

- High blocking voltage capability
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Surface-mountable package
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|------------------------------------------|--------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 102 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 8 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 65 | Α |
| | | full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms | - | - | 71 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| Static chara | acteristics | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u> | - | 30 | 70 | mA |

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| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------------|---------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|--|-----|-----|------|------|
| Ι _Η | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | | - | 5 | 20 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u> | | - | 1.3 | 1.65 | V |
| Dynamic characteristics | | | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | | 100 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_{D} = 400 V; T_{j} = 95 °C; dI_{com}/dt = 3.6 A/ ms; I_T = 8 A; gate open circuit | | - | 20 | - | V/µs |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--------------------|----------------|
| 1 | T1 | main terminal 1 | [] | T2 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | Symoor |
| mb | Τ2 | mounting base; main terminal 2 | DPAK (SOT428) | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|---------|---------------------------------------------------------------------------------|---------|--|--|--|
| Type number | Package | :kage | | | | |
| | Name | Description | Version | | | |
| BT137S-600 | DPAK | plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) | SOT428 | | | |



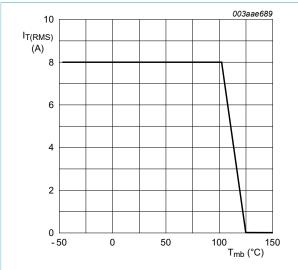
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7. Limiting values

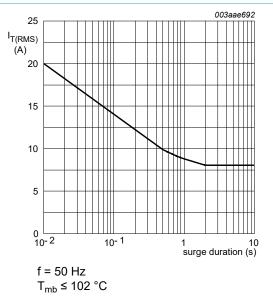
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|------------------------------------------|-----------------------------------------------------------------------------------|-----|-----|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 102 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | 8 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | 65 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 71 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 21 | A²s |
| dl _T /dt | rate of rise of on-state current | I _G = 150 mA | - | 50 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Т _і | junction temperature | | - | 125 | °C |

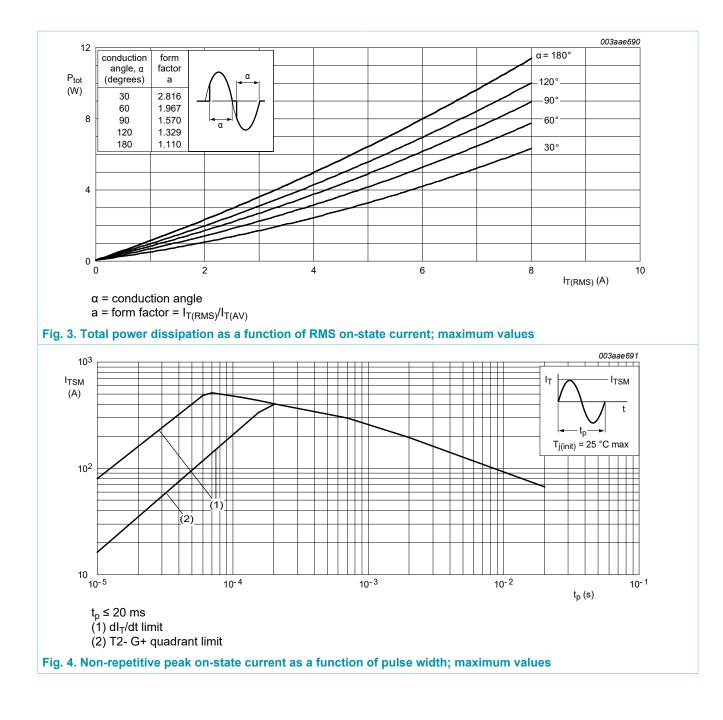








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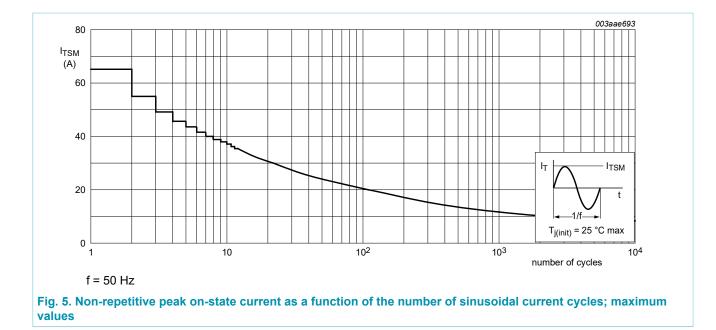


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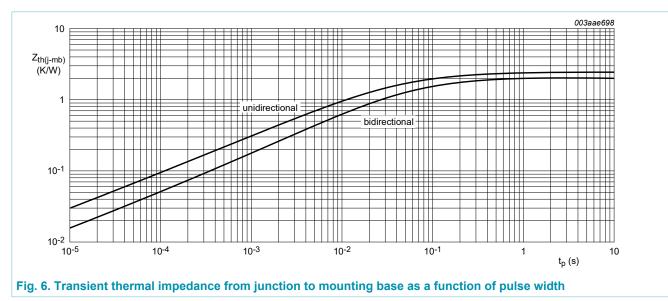
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8. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|------------------------------------------------------------|--------------------------------------|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | half cycle; <u>Fig. 6</u> | - | - | 2.4 | K/W |
| | | full cycle; <u>Fig. 6</u> | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient free air | PCB (FR4) mounted; minimum pad sizes | - | 75 | - | K/W |



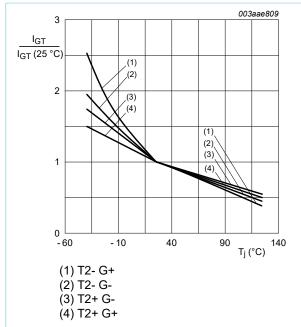
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9. Characteristics

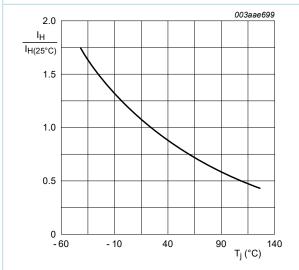
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|------|-----|------|------|
| Static chara | octeristics | | | | | |
| I _{GT} | gate trigger current | $V_D = 12 V; I_T = 0.1 A; T2+G+;$ T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 11 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 30 | 70 | mA |
| IL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 30 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | 16 | 45 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | 5 | 30 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 45 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 5 | 20 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.65 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic ch | aracteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 100 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | V_D = 400 V; T _j = 95 °C; dI _{com} /dt = 3.6 A/ ms; I _T = 8 A; gate open circuit | - | 20 | - | V/µs |

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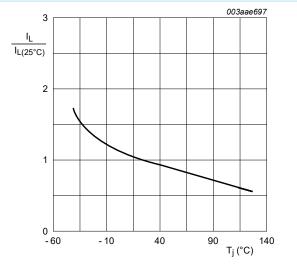
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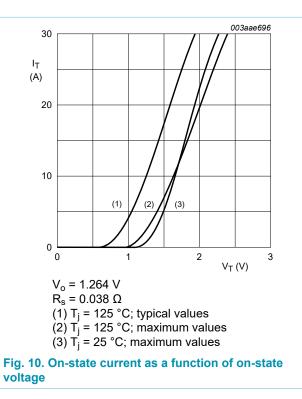








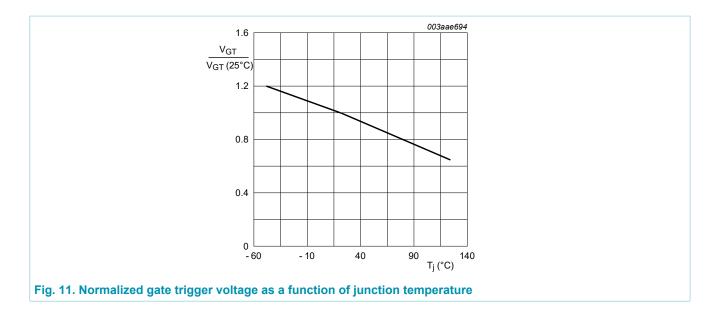




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10. Package outline

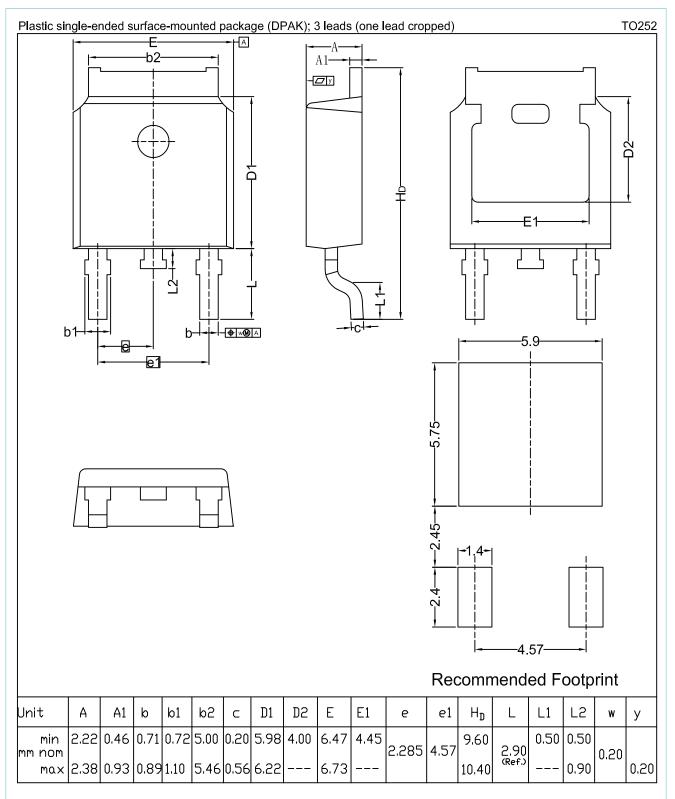


Fig. 12. Package outline DPAK (SOT428)

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| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---------------------------------------------------------------------------------------------|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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